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Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

E·XFI

Product Status	Discontinued at Digi-Key
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	CANbus, I ² C, IrDA, LINbus, SmartCard, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, I ² S, POR, PWM, WDT
Number of I/O	24
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.8V
Data Converters	A/D 12bit SAR; D/A 12bit
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	32-WFQFN Exposed Pad
Supplier Device Package	32-QFN (5x5)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm32tg11b120f128gm32-ar

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Timers/Counters

- 2 × 16-bit Timer/Counter
 - 3 or 4 Compare/Capture/PWM channels (4 + 4 on one timer instance)
 - Dead-Time Insertion on one timer instance
- 2 × 32-bit Timer/Counter
- 32-bit Real Time Counter and Calendar (RTCC)
- 32-bit Ultra Low Energy CRYOTIMER for periodic wakeup from any Energy Mode
- 16-bit Low Energy Timer for waveform generation
- 16-bit Pulse Counter with asynchronous operation
- Watchdog Timer with dedicated RC oscillator
- Low Energy Sensor Interface (LESENSE)
 - Autonomous sensor monitoring in Deep Sleep Mode
 - Wide range of sensors supported, including LC sensors and capacitive buttons
 - Up to 16 inputs
- Ultra efficient Power-on Reset and Brown-Out Detector
- Debug Interface
 - 2-pin Serial Wire Debug interface
 - 4-pin JTAG interface
 - Micro Trace Buffer (MTB)

Pre-Programmed UART Bootloader

Wide Operating Range

- 1.8 V to 3.8 V single power supply
- Integrated DC-DC, down to 1.8 V output with up to 200 mA load current for system
- Standard (-40 $^\circ C$ to 85 $^\circ C$ $T_A)$ and Extended (-40 $^\circ C$ to 125 $^\circ C$ $T_J)$ temperature grades available
- Packages
 - QFN32 (5x5 mm)
 - TQFP48 (7x7 mm)
 - QFN64 (9x9 mm)
 - TQFP64 (10x10 mm)
 - QFN80 (9x9 mm)
 - TQFP80 (12x12 mm)

3.3 General Purpose Input/Output (GPIO)

EFM32TG11 has up to 67 General Purpose Input/Output pins. Each GPIO pin can be individually configured as either an output or input. More advanced configurations including open-drain, open-source, and glitch-filtering can be configured for each individual GPIO pin. The GPIO pins can be overridden by peripheral connections, like SPI communication. Each peripheral connection can be routed to several GPIO pins on the device. The input value of a GPIO pin can be routed through the Peripheral Reflex System to other peripherals. The GPIO subsystem supports asynchronous external pin interrupts.

3.4 Clocking

3.4.1 Clock Management Unit (CMU)

The Clock Management Unit controls oscillators and clocks in the EFM32TG11. Individual enabling and disabling of clocks to all peripheral modules is performed by the CMU. The CMU also controls enabling and configuration of the oscillators. A high degree of flexibility allows software to optimize energy consumption in any specific application by minimizing power dissipation in unused peripherals and oscillators.

3.4.2 Internal and External Oscillators

The EFM32TG11 supports two crystal oscillators and fully integrates four RC oscillators, listed below.

- A high frequency crystal oscillator (HFXO) with integrated load capacitors, tunable in small steps, provides a precise timing reference for the MCU. Crystal frequencies in the range from 4 to 48 MHz are supported. An external clock source such as a TCXO can also be applied to the HFXO input for improved accuracy over temperature.
- A 32.768 kHz crystal oscillator (LFXO) provides an accurate timing reference for low energy modes.
- An integrated high frequency RC oscillator (HFRCO) is available for the MCU system. The HFRCO employs fast startup at minimal energy consumption combined with a wide frequency range. When crystal accuracy is not required, it can be operated in free-running mode at a number of factory-calibrated frequencies. A digital phase-locked loop (DPLL) feature allows the HFRCO to achieve higher accuracy and stability by referencing other available clock sources such as LFXO and HFXO.
- An integrated auxiliary high frequency RC oscillator (AUXHFRCO) is available for timing the general-purpose ADC with a wide frequency range.
- An integrated low frequency 32.768 kHz RC oscillator (LFRCO) can be used as a timing reference in low energy modes, when crystal accuracy is not required.
- An integrated ultra-low frequency 1 kHz RC oscillator (ULFRCO) is available to provide a timing reference at the lowest energy consumption in low energy modes.

3.5 Counters/Timers and PWM

3.5.1 Timer/Counter (TIMER)

TIMER peripherals keep track of timing, count events, generate PWM outputs and trigger timed actions in other peripherals through the PRS system. The core of each TIMER is a 16-bit counter with up to 4 compare/capture channels. Each channel is configurable in one of three modes. In capture mode, the counter state is stored in a buffer at a selected input event. In compare mode, the channel output reflects the comparison of the counter to a programmed threshold value. In PWM mode, the TIMER supports generation of pulse-width modulation (PWM) outputs of arbitrary waveforms defined by the sequence of values written to the compare registers, with optional dead-time insertion available in timer unit TIMER_0 only.

3.5.2 Wide Timer/Counter (WTIMER)

WTIMER peripherals function just as TIMER peripherals, but are 32 bits wide. They keep track of timing, count events, generate PWM outputs and trigger timed actions in other peripherals through the PRS system. The core of each WTIMER is a 32-bit counter with up to 4 compare/capture channels. Each channel is configurable in one of three modes. In capture mode, the counter state is stored in a buffer at a selected input event. In compare mode, the channel output reflects the comparison of the counter to a programmed threshold value. In PWM mode, the WTIMER supports generation of pulse-width modulation (PWM) outputs of arbitrary waveforms defined by the sequence of values written to the compare registers, with optional dead-time insertion available in timer unit WTIMER_0 only.

3.5.3 Real Time Counter and Calendar (RTCC)

The Real Time Counter and Calendar (RTCC) is a 32-bit counter providing timekeeping in all energy modes. The RTCC includes a Binary Coded Decimal (BCD) calendar mode for easy time and date keeping. The RTCC can be clocked by any of the on-board oscillators with the exception of the AUXHFRCO, and it is capable of providing system wake-up at user defined instances. The RTCC includes 128 bytes of general purpose data retention, allowing easy and convenient data storage in all energy modes down to EM4H.

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Current consumption in EM4H mode, with voltage scaling enabled	I _{EM4H_VS}	128 byte RAM retention, RTCC running from LFXO	_	0.82	—	μA
		128 byte RAM retention, CRYO- TIMER running from ULFRCO	_	0.45	_	μA
		128 byte RAM retention, no RTCC	_	0.45	TBD	μA
Current consumption in EM4S mode	I _{EM4S}	No RAM retention, no RTCC	_	0.07	TBD	μA
Current consumption of pe- ripheral power domain 1, with voltage scaling enabled	IPD1_VS	Additional current consumption in EM2/3 when any peripherals on power domain 1 are enabled ¹	_	0.18	—	μA
Current consumption of pe- ripheral power domain 2, with voltage scaling enabled	IPD2_VS	Additional current consumption in EM2/3 when any peripherals on power domain 2 are enabled ¹	_	0.18	_	μA

Note:

1. Extra current consumed by power domain. Does not include current associated with the enabled peripherals. See 3.2.3 EM2 and EM3 Power Domains for a list of the peripherals in each power domain.

2. CMU_LFRCOCTRL_ENVREF = 1, CMU_LFRCOCTRL_VREFUPDATE = 1

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Current consumption in EM4H mode, with voltage scaling enabled	I _{EM4H_VS}	128 byte RAM retention, RTCC running from LFXO	_	0.75	—	μA
		128 byte RAM retention, CRYO- TIMER running from ULFRCO	—	0.37	_	μA
		128 byte RAM retention, no RTCC	_	0.37	_	μA
Current consumption in EM4S mode	I _{EM4S}	No RAM retention, no RTCC	—	0.05	—	μA
Current consumption of pe- ripheral power domain 1, with voltage scaling enabled	IPD1_VS	Additional current consumption in EM2/3 when any peripherals on power domain 1 are enabled ¹	_	0.18	_	μA
Current consumption of pe- ripheral power domain 2, with voltage scaling enabled	IPD2_VS	Additional current consumption in EM2/3 when any peripherals on power domain 2 are enabled ¹	_	0.18	—	μA

Note:

1. Extra current consumed by power domain. Does not include current associated with the enabled peripherals. See 3.2.3 EM2 and EM3 Power Domains for a list of the peripherals in each power domain.

2. CMU_LFRCOCTRL_ENVREF = 1, CMU_LFRCOCTRL_VREFUPDATE = 1

4.1.9.5 Auxiliary High-Frequency RC Oscillator (AUXHFRCO)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Frequency accuracy	f _{AUXHFRCO_ACC}	At production calibrated frequen- cies, across supply voltage and temperature	TBD	_	TBD	%
Start-up time	t _{AUXHFRCO}	f _{AUXHFRCO} ≥ 19 MHz	_	400	_	ns
		4 < f _{AUXHFRCO} < 19 MHz	_	1.4	_	μs
		f _{AUXHFRCO} ≤ 4 MHz	_	2.5		μs
Current consumption on all	IAUXHFRCO	f _{AUXHFRCO} = 48 MHz	_	238	TBD	μA
supplies		f _{AUXHFRCO} = 38 MHz	—	196	TBD	μA
		f _{AUXHFRCO} = 32 MHz		160	TBD	μA
		f _{AUXHFRCO} = 26 MHz	_	137	TBD	μA
		f _{AUXHFRCO} = 19 MHz	—	110	TBD	μA
		f _{AUXHFRCO} = 16 MHz	_	101	TBD	μA
		f _{AUXHFRCO} = 13 MHz	_	78	TBD	μA
		f _{AUXHFRCO} = 7 MHz	—	54	TBD	μA
		f _{AUXHFRCO} = 4 MHz	_	30	TBD	μA
		f _{AUXHFRCO} = 2 MHz	_	27	TBD	μA
		f _{AUXHFRCO} = 1 MHz	_	25	TBD	μA
Coarse trim step size (% of period)	SS _{AUXHFR-} CO_COARSE		_	0.8	_	%
Fine trim step size (% of pe- riod)	SS _{AUXHFR-} CO_FINE		—	0.1	_	%
Period jitter	PJ _{AUXHFRCO}		—	0.2	—	% RMS

Table 4.15. Auxiliary High-Frequency RC Oscillator (AUXHFRCO)

4.1.9.6 Ultra-low Frequency RC Oscillator (ULFRCO)

Table 4.16. Ultra-low Frequency RC Oscillator (ULFRCO)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Oscillation frequency	f _{ULFRCO}		TBD	1	TBD	kHz

4.1.13 Analog to Digital Converter (ADC)

Specified at 1 Msps, ADCCLK = 16 MHz, BIASPROG = 0, GPBIASACC = 0, unless otherwise indicated.

Table 4.20. Analog to Digital Converter (ADC)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Resolution	VRESOLUTION		6	_	12	Bits
Input voltage range ⁵	V _{ADCIN}	Single ended	—	—	V _{FS}	V
		Differential	-V _{FS} /2		V _{FS} /2	V
Input range of external refer- ence voltage, single ended and differential	Vadcrefin_p		1	—	V _{AVDD}	V
Power supply rejection ²	PSRR _{ADC}	At DC	—	80	_	dB
Analog input common mode rejection ratio	CMRR _{ADC}	At DC	_	80	_	dB
Current from all supplies, us- ing internal reference buffer.	I _{ADC_CONTI-} NOUS_LP	1 Msps / 16 MHz ADCCLK, BIA- SPROG = 0, GPBIASACC = 1 ³	_	270	TBD	μA
MUPMODE ⁴ = KEEPADC- WARM		250 ksps / 4 MHz ADCCLK, BIA- SPROG = 6, GPBIASACC = 1 ³	_	125	_	μA
		62.5 ksps / 1 MHz ADCCLK, BIA- SPROG = 15, GPBIASACC = 1 ³	_	80	-	μA
Current from all supplies, us- ing internal reference buffer.	IADC_NORMAL_LP	35 ksps / 16 MHz ADCCLK, BIA- SPROG = 0, GPBIASACC = 1 ³	—	45	_	μA
MUPMODE ⁴ = NORMAL		5 ksps / 16 MHz ADCCLK BIA- SPROG = 0, GPBIASACC = 1 ³	_	8	_	μA
Current from all supplies, using internal reference buffer.	I _{ADC_STAND-} BY_LP	125 ksps / 16 MHz ADCCLK, BIA- SPROG = 0, GPBIASACC = 1 ³	_	105	-	μA
AWARMUPMODE ⁴ = KEEP- INSTANDBY or KEEPIN- SLOWACC		35 ksps / 16 MHz ADCCLK, BIA- SPROG = 0, GPBIASACC = 1 ³	_	70	_	μA
Current from all supplies, us- ing internal reference buffer.	I _{ADC_CONTI-} NOUS_HP	1 Msps / 16 MHz ADCCLK, BIA- SPROG = 0, GPBIASACC = 0 ³		325	-	μA
MUPMODE ⁴ = KEEPADC- WARM		250 ksps / 4 MHz ADCCLK, BIA-SPROG = 6, GPBIASACC = 0 3	_	175	_	μA
		62.5 ksps / 1 MHz ADCCLK, BIA- SPROG = 15, GPBIASACC = 0 ³	_	125	-	μA
Current from all supplies, us- ing internal reference buffer.	IADC_NORMAL_HP	35 ksps / 16 MHz ADCCLK, BIA-SPROG = 0, GPBIASACC = 0 3	_	85	_	μA
Duty-cycled operation. WAR- MUPMODE ⁴ = NORMAL		5 ksps / 16 MHz ADCCLK BIA- SPROG = 0, GPBIASACC = 0 ³	_	16	_	μA
Current from all supplies, using internal reference buffer.	I _{ADC_STAND} - BY_HP	125 ksps / 16 MHz ADCCLK, BIA- SPROG = 0, GPBIASACC = 0 ³	_	160	-	μA
AWARMUPMODE ⁴ = KEEP- INSTANDBY or KEEPIN- SLOWACC		35 ksps / 16 MHz ADCCLK, BIA- SPROG = 0, GPBIASACC = 0 ³	_	125	-	μA
Current from HFPERCLK	IADC_CLK	HFPERCLK = 16 MHz	_	166	_	μA

4.1.14 Analog Comparator (ACMP)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Input voltage range	V _{ACMPIN}	ACMPVDD = ACMPn_CTRL_PWRSEL ¹	—	—	V _{ACMPVDD}	V
Supply voltage	VACMPVDD	$BIASPROG^4 \le 0x10 \text{ or } FULL-BIAS^4 = 0$	1.8	—	V _{VREGVDD} MAX	V
		$0x10 < BIASPROG^4 \le 0x20$ and FULLBIAS ⁴ = 1	2.1	_	V _{VREGVDD} MAX	V
Active current not including	I _{ACMP}	$BIASPROG^4 = 1$, $FULLBIAS^4 = 0$	—	50	_	nA
voltage reference ²		$BIASPROG^4 = 0x10, FULLBIAS^4 = 0$		306	_	nA
		$BIASPROG^4 = 0x02, FULLBIAS^4$ $= 1$	_	6.5	_	μA
		BIASPROG ⁴ = 0x20, FULLBIAS ⁴ = 1	_	74	TBD	μA
Current consumption of inter- nal voltage reference ²	IACMPREF	VLP selected as input using 2.5 V Reference / 4 (0.625 V)	_	50	_	nA
		VLP selected as input using VDD	—	20	_	nA
		VBDIV selected as input using 1.25 V reference / 1	—	4.1	_	μA
		VADIV selected as input using VDD/1		2.4	_	μA

Table 4.21. Analog Comparator (ACMP)

4.1.15 Digital to Analog Converter (VDAC)

DRIVESTRENGTH = 2 unless otherwise specified. Primary VDAC output.

Table 4.22.	Digital to	Analog Converter	(VDAC)
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Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Output voltage	V _{DACOUT}	Single-Ended	0	_	V _{VREF}	V
		Differential ²	-V _{VREF}	—	V _{VREF}	V
Current consumption includ- ing references (2 channels) ¹	I _{DAC}	500 ksps, 12-bit, DRIVES- TRENGTH = 2, REFSEL = 4	_	396	_	μΑ
		44.1 ksps, 12-bit, DRIVES- TRENGTH = 1, REFSEL = 4	—	72	—	μA
		200 Hz refresh rate, 12-bit Sam- ple-Off mode in EM2, DRIVES- TRENGTH = 2, BGRREQTIME = 1, EM2REFENTIME = 9, REFSEL = 4, SETTLETIME = 0x0A, WAR- MUPTIME = 0x02	_	2	_	μA
Current from HFPERCLK ⁴	IDAC_CLK		_	5.8		µA/MHz
Sample rate	SR _{DAC}		—	—	500	ksps
DAC clock frequency	f _{DAC}		—	—	1	MHz
Conversion time	t _{DACCONV}	f _{DAC} = 1MHz	2	_	_	μs
Settling time	t _{DACSETTLE}	50% fs step settling to 5 LSB		2.5		μs
Startup time	t _{DACSTARTUP}	Enable to 90% fs output, settling to 10 LSB	—	—	12	μs
Output impedance	R _{OUT}	$\label{eq:output} \begin{array}{l} DRIVESTRENGTH = 2,\ 0.4\ V \leq \\ V_{OUT} \leq V_{OPA} - 0.4\ V, -8\ mA < \\ I_{OUT} < 8\ mA, \ Full \ supply \ range \end{array}$	_	2	_	Ω
		DRIVESTRENGTH = 0 or 1, 0.4 V $\leq V_{OUT} \leq V_{OPA} - 0.4 V$, -400 µA < $I_{OUT} < 400$ µA, Full supply range	_	2	_	Ω
		$\begin{array}{l} DRIVESTRENGTH = 2, \ 0.1 \ V \leq \\ V_{OUT} \leq V_{OPA} \ \text{-} \ 0.1 \ V, \ \text{-} 2 \ mA < \\ I_{OUT} < 2 \ mA, \ Full \ supply \ range \end{array}$		2	_	Ω
		DRIVESTRENGTH = 0 or 1, 0.1 V $\leq V_{OUT} \leq V_{OPA} - 0.1 V$, -100 µA < $I_{OUT} < 100$ µA, Full supply range	_	2	_	Ω
Power supply rejection ratio ⁶	PSRR	Vout = 50% fs. DC		65.5	_	dB

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Note:						
 Supply current specification the load. 	ons are for VDAC	circuitry operating with static output o	only and do no	ot include curi	rent required	to drive
2. In differential mode, the o limited to the single-ender	utput is defined as d range.	the difference between two single-e	nded outputs	. Absolute vol	tage on each	output is
3. Entire range is monotonic	and has no missir	ng codes.				
4. Current from HFPERCLK the clock to the DAC mod	is dependent on H lule is enabled in th	IFPERCLK frequency. This current c ne CMU.	contributes to	the total supp	ly current use	ed when
5. Gain is calculated by mea 10% of full scale to ideal	asuring the slope fr VDAC output at 10	om 10% to 90% of full scale. Offset i % of full scale with the measured ga	is calculated t in.	by comparing	actual VDAC	output at
6. PSRR calculated as 20 *	log ₁₀ (ΔVDD / ΔV _O	_{UT}), VDAC output at 90% of full scale	е			

4.1.21.3 I2C Fast-mode Plus (Fm+)¹

Parameter	Symbol	Test Condition	Min	Тур	Мах	Unit
SCL clock frequency ²	f _{SCL}		0	_	1000	kHz
SCL clock low time	t _{LOW}		0.5	_	_	μs
SCL clock high time	t _{HIGH}		0.26	_	_	μs
SDA set-up time	t _{SU_DAT}		50	_	—	ns
SDA hold time	t _{HD_DAT}		100	_	—	ns
Repeated START condition set-up time	t _{SU_STA}		0.26	_	_	μs
(Repeated) START condition hold time	t _{HD_STA}		0.26	_	—	μs
STOP condition set-up time	t _{SU_STO}		0.26	_	_	μs
Bus free time between a STOP and START condition	t _{BUF}		0.5	—	—	μs

Table 4.30. I2C Fast-mode Plus (Fm+)¹

Note:

1. For CLHR set to 0 or 1 in the I2Cn_CTRL register.

2. For the minimum HFPERCLK frequency required in Fast-mode Plus, refer to the I2C chapter in the reference manual.

Parameter	Symbol	Test Condition	Min	Тур	Мах	Unit
SCLK period ^{1 3 2}	t _{SCLK}		6 * t _{HFPERCLK}	—	_	ns
SCLK high time ^{1 3 2}	t _{SCLK_HI}		2.5 * t _{HFPERCLK}	_	_	ns
SCLK low time ^{1 3 2}	t _{SCLK_LO}		2.5 * t _{HFPERCLK}	—	—	ns
CS active to MISO ^{1 3}	t _{CS_ACT_MI}		20	_	70	ns
CS disable to MISO ^{1 3}	t _{CS_DIS_MI}		15		150	ns
MOSI setup time ^{1 3}	t _{SU_MO}		4		_	ns
MOSI hold time ^{1 3 2}	t _{H_MO}		7	_	_	ns
SCLK to MISO ^{1 3 2}	t _{SCLK_MI}		14 + 1.5 * t _{HFPERCLK}	_	40 + 2.5 * t _{HFPERCLK}	ns

Table 4.32. SPI Slave Timing

Note:

1. Applies for both CLKPHA = 0 and CLKPHA = 1 (figure only shows CLKPHA = 0).

2. $t_{\mbox{\scriptsize HFPERCLK}}$ is one period of the selected $\mbox{\scriptsize HFPERCLK}.$

3. Measurement done with 8 pF output loading at 10% and 90% of V_{DD} (figure shows 50% of V_{DD}).



Figure 4.2. SPI Slave Timing Diagram

4.2 Typical Performance Curves

Typical performance curves indicate typical characterized performance under the stated conditions.



Figure 5.3. EFM32TG11B5xx in QFP64 Device Pinout

The following table provides package pin connections and general descriptions of pin functionality. For detailed information on the supported features for each GPIO pin, see 5.14 GPIO Functionality Table or 5.15 Alternate Functionality Overview.

Table 5.3. EFM32TG	11B5xx in QFP6	4 Device Pinout
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Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PA0	1	GPIO	PA1	2	GPIO
PA2	3	GPIO	PA3	4	GPIO
PA4	5	GPIO	PA5	6	GPIO
IOVDD0	7 27 55	Digital IO power supply 0.	VSS	8 23 56	Ground
PB3	9	GPIO	PB4	10	GPIO
PB5	11	GPIO	PB6	12	GPIO



Figure 5.9. EFM32TG11B5xx in QFP48 Device Pinout

The following table provides package pin connections and general descriptions of pin functionality. For detailed information on the supported features for each GPIO pin, see 5.14 GPIO Functionality Table or 5.15 Alternate Functionality Overview.

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PA0	1	GPIO	PA1	2	GPIO
PA2	3	GPIO	IOVDD0	4 21 43	Digital IO power supply 0.
VSS	5 17 44	Ground	PB3	6	GPIO
PB4	7	GPIO	PB5	8	GPIO
PB6	9	GPIO	PB7	10	GPIO

Alternate	LOCA	ATION							
Functionality	0 - 3	4 - 7	Description						
CAN0_TX	0: PC1 1: PF2 2: PD1		CAN0 TX.						
CMU_CLK0	0: PA2 1: PC12 2: PD7	4: PF2 5: PA12	Clock Management Unit, clock output number 0.						
CMU_CLK1	0: PA1 1: PD8 2: PE12	4: PF3 5: PB11	Clock Management Unit, clock output number 1.						
CMU_CLK2	0: PA0 1: PA3 2: PD6	4: PA3	Clock Management Unit, clock output number 2.						
CMU_CLKI0	0: PD4 1: PA3 2: PB8 3: PB13	6: PE12 7: PB11	Clock Management Unit, clock input number 0.						
DBG_SWCLKTCK	0: PF0		Debug-interface Serial Wire clock input and JTAG Test Clock. Note that this function is enabled to the pin out of reset, and has a built-in pull down.						
DBG_SWDIOTMS	0: PF1		Debug-interface Serial Wire data input / output and JTAG Test Mode Select. Note that this function is enabled to the pin out of reset, and has a built-in pull up.						
DBG_TDI	0: PF5		Debug-interface JTAG Test Data In. Note that this function becomes available after the first valid JTAG command is re- ceived, and has a built-in pull up when JTAG is active.						
DBG_TDO	0: PF2		Debug-interface JTAG Test Data Out. Note that this function becomes available after the first valid JTAG command is re- ceived.						
GPIO_EM4WU0	0: PA0		Pin can be used to wake the system up from EM4						
GPIO_EM4WU1	0: PA6		Pin can be used to wake the system up from EM4						
GPIO_EM4WU2	0: PC9		Pin can be used to wake the system up from EM4						
GPIO_EM4WU3	0: PF1		Pin can be used to wake the system up from EM4						

Alternate	LOCA		
Functionality	0 - 3	4 - 7	Description
LCD_SEG22 / LCD_COM6	0: PB5		LCD segment line 22. This pin may also be used as LCD COM line 6
LCD_SEG23 / LCD_COM7	0: PB6		LCD segment line 23. This pin may also be used as LCD COM line 7
LCD_SEG24	0: PC4		LCD segment line 24.
LCD_SEG25	0: PC5		LCD segment line 25.
LCD_SEG26	0: PA9		LCD segment line 26.
LCD_SEG27	0: PA10		LCD segment line 27.
LCD_SEG28	0: PB11		LCD segment line 28.
LCD_SEG29	0: PB12		LCD segment line 29.
LCD_SEG30	0: PD3		LCD segment line 30.
LCD_SEG31	0: PD4		LCD segment line 31.
LCD_SEG32	0: PC6		LCD segment line 32.
LCD_SEG33	0: PC7		LCD segment line 33.
LCD_SEG34	0: PC8		LCD segment line 34.

Alternate	LOCATION								
Functionality	0 - 3	4 - 7	Description						
VDAC0_OUT0 / OPA0_OUT	0: PB11		Digital to Analog Converter DAC0 output channel number 0.						
VDAC0_OUT0ALT / OPA0_OUTALT	0: PC0 1: PC1 2: PC2 3: PC3	4: PD0	Digital to Analog Converter DAC0 alternative output for channel 0.						
VDAC0_OUT1 / OPA1_OUT	0: PB12		Digital to Analog Converter DAC0 output channel number 1.						
VDAC0_OUT1ALT / OPA1_OUTALT	0: PC12 1: PC13 2: PC14 3: PC15	4: PD1	Digital to Analog Converter DAC0 alternative output for channel 1.						
WTIM0_CC0	0: PE4 1: PA6	4: PC15 6: PB3 7: PC1	Wide timer 0 Capture Compare input / output channel 0.						
WTIM0_CC1	0: PE5	4: PF0 6: PB4 7: PC2	Wide timer 0 Capture Compare input / output channel 1.						
WTIM0_CC2	0: PE6	4: PF1 6: PB5 7: PC3	Wide timer 0 Capture Compare input / output channel 2.						
WTIM0_CDTI0	0: PE10 2: PA12	4: PD4	Wide timer 0 Complimentary Dead Time Insertion channel 0.						
WTIM0_CDTI1	0: PE11 2: PA13	4: PD5	Wide timer 0 Complimentary Dead Time Insertion channel 1.						
WTIM0_CDTI2	0: PE12 2: PA14	4: PD6	Wide timer 0 Complimentary Dead Time Insertion channel 2.						
WTIM1_CC0	0: PB13 1: PD2 2: PD6 3: PC7	5: PE7	Wide timer 1 Capture Compare input / output channel 0.						
WTIM1_CC1	0: PB14 1: PD3 2: PD7	4: PE4	Wide timer 1 Capture Compare input / output channel 1.						
WTIM1_CC2	0: PD0 1: PD4 2: PD8	4: PE5	Wide timer 1 Capture Compare input / output channel 2.						

Port	Bus	CH31	CH30	CH29	CH28	CH27	CH26	CH25	CH24	CH23	CH22	CH21	CH20	CH19	CH18	CH17	CH16	CH15	CH14	CH13	CH12	CH11	CH10	СН9	CH8	CH7	CH6	CH5	CH4	CH3	CH2	CH1	СНО
APORT0X	BUSACMP1X																									PC15	PC14	PC13	PC12	PC11	PC10	PC9	PC8
APORT0Y	BUSACMP1Y																									PC15	PC14	PC13	PC12	PC11	PC10	PC9	PC8
APORT1X	BUSAX		PB14		PB12						PB6		PB4						PA14				PA10				PA6		PA4		PA2		PA0
APORT1Y	BUSAY			PB13		PB11						PB5		PB3				PA15		PA13				PA9				PA5		PA3		PA1	
APORT2X	BUSBX			PB13		PB11						PB5		PB3				PA15		PA13				PA9				PA5		PA3		PA1	
APORT2Y	BUSBY		PB14		PB12						PB6		PB4						PA14				PA10				PA6		PA4		PA2		PA0
APORT3X	BUSCX												PF4		PF2		PF0		PE14		PE12		PE10		PE8		PE6		PE4				
APORT3Y	BUSCY											PF5		PF3		PF1		PE15		PE13		PE11		PE9		PE7		PE5					
APORT4X	BUSDX											PF5		PF3		PF1		PE15		PE13		PE11		PE9		PE7		PE5					
APORT4Y	BUSDY												PF4		PF2		PF0		PE14		PE12		PE10		PE8		PE6		PE4				

Table 5.17. ACMP1 Bus and Pin Mapping

6. TQFP80 Package Specifications

6.1 TQFP80 Package Dimensions



Figure 6.1. TQFP80 Package Drawing

Table 7.2. QFN80 PCB Land Pattern Dimensions

Dimension	Тур
C1	8.90
C2	8.90
E	0.40
X1	0.20
Y1	0.85
X2	7.30
Y2	7.30

Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. This Land Pattern Design is based on the IPC-7351 guidelines.

3. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05mm.

4. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 μm minimum, all the way around the pad.

5. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.

6. The stencil thickness should be 0.125 mm (5 mils).

7. The ratio of stencil aperture to land pad size can be 1:1 for all pads.

8. A 3x3 array of 1.45 mm square openings on a 2.00 mm pitch can be used for the center ground pad.

9. A No-Clean, Type-3 solder paste is recommended.

10. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.



Figure 7.3. QFN80 Package Marking

The package marking consists of:

- PPPPPPPPP The part number designation.
- TTTTTT A trace or manufacturing code. The first letter is the device revision.
- YY The last 2 digits of the assembly year.
- WW The 2-digit workweek when the device was assembled.